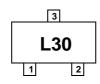


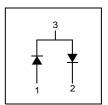
BAV23S Small Signal Diode







Connection Diagram



Absolute Maximum Ratings * Ta = 25°C unless otherwise noted

Symbol	Parameter	Value	Unit
V_{RRM}	Maximum Repetitive Reverse Voltage 250		V
I _{F(AV)}	Average Rectified Forward Current	200	mA
I _{FSM}	Non-repetitive Peak Forward Surge Current Pulse Width = 1.0 microsecond Pulse Width = 100 microsecond	9.0 3.0	A A
T _{STG}	Storage Temperature Range	-55 to +150	°C
TJ	Operating Junction Temperature	150	°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics

Symbol	Parameter	Value	Unit
P_{D}	Power Dissipation	350	mW
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient*	357	°C/W

Electrical Characteristics $T_C = 25$ $^{\circ}$ C unless otherwise noted

Symbol	Parameter	Conditions	Min.	Max	Units
V_R	Breakdown Voltage	I _R = 100μA	250		V
V _F	Forward Voltage	I _F = 100mA I _F = 200mA		1.0 1.25	V V
I _R	Reverse Leakage	V _R = 250V V _R = 250V, T _A = 150°C		100 100	nA μA
t _{rr}	Reverse Recovery Time	$I_F = I_R = 30 \text{mA}, I_{RR} = 3.0 \text{mA}, R_L = 100 \Omega$		50	ns

Typical Performance Characteristics

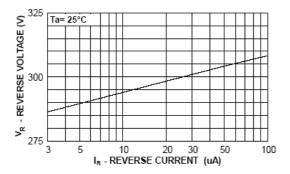
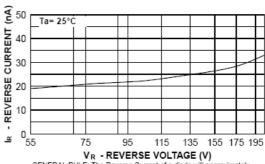


Figure 1. Reverse Voltage vs Reverse Current BV - 1.0 to $100 \mu A$



GENERAL RULE: The Reverse Current of a diode will approximately double for every ten (10) Degree C increase in Temperature

Figure 2. Reverse Current vs Reverse Voltage IR - 55 to 205V

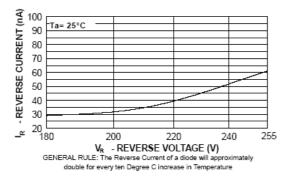


Figure 3. Reverse Current vs Reverse Voltage IR - 180 to 255V

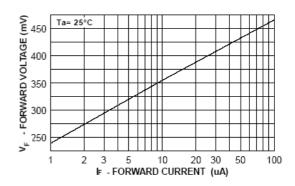


Figure 4. Forward Voltage vs Forward Current VF - 1.0 to 100μA

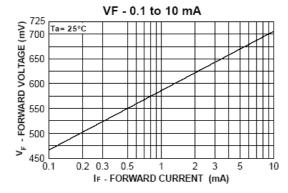


Figure 5. Forward Voltage vs Forward Current VF - 0.1 to 10mA

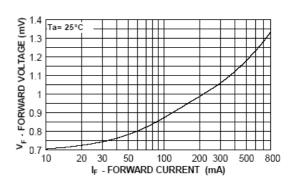


Figure 6. Forward Voltage vs Forward Current VF - 10 to 800mA

Typical Performance Characteristics (Continued)

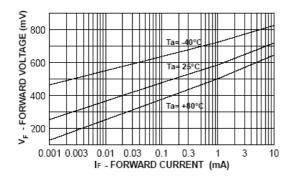


Figure 7. Forward Voltage vs Ambient Temperature VF - 1.0μA - 10mA (- 40 to +80°C)

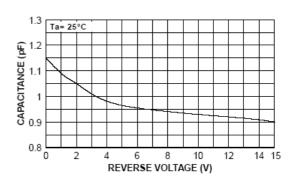


Figure 8. Capacitance vs Reverse Voltage VR - 0 to 5V

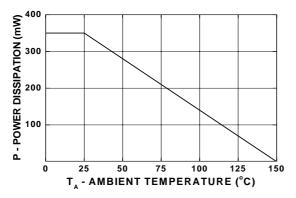


Figure 9. Power Derating Curve

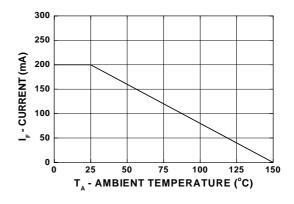


Figure 10. Average Rectified Current(I_O) vs Ambient Temperature(T_A)

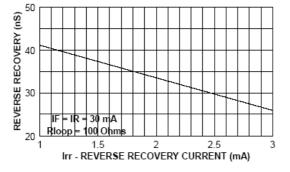
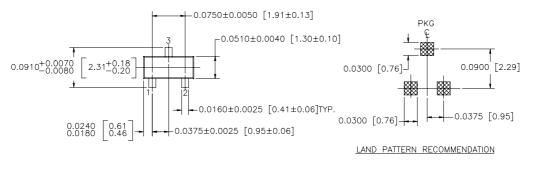
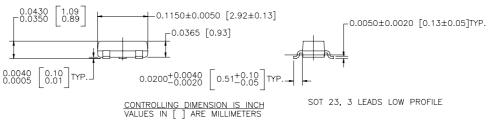


Figure 11. Reverse Recovery Time vs Reverse Recovery Current (Irr)

Mechanical Dimensions

SOT-23





NOTE: UNLESS OTHERWISE SPECIFIED

- 1. STANDARD LEAD FINISH 150 MICROINCHES / 3.81 MICROMETERS MINIMUM TIN / LEAD (SOLDER) ON ALLOY 42
- 2. REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE G, DATED JUL 1993

UltraFET®

UniFET™

 VCX^{TM}

Wire™

TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

 $ACEx^{TM}$ OCX^{TM} SILENT SWITCHER® FACT Quiet Series™ OCXPro[™] ActiveArray™ GlobalOptoisolator™ SMART START™ OPTOLOGIC® GTO™ SPM™ Bottomless™ HiSeC™ OPTOPLANAR™ Build it Now™ Stealth™ I²C™ PACMANTM CoolFET™ SuperFET™ РОР™ $CROSSVOLT^{\rm TM}$ i-Lo™ SuperSOT™-3 Power247™ DOME™ ImpliedDisconnect™ SuperSOT™-6 EcoSPARK™ PowerEdge™ SuperSOT™-8 IntelliMAX™ $\mathsf{E}^2\mathsf{CMOS^{\mathsf{TM}}}$ ISOPLANAR™ PowerSaver™ SyncFET™ PowerTrench® ТСМ™ EnSigna™ LittleFET™ FACT™ $\mathsf{MICROCOUPLER}^{\mathsf{TM}}$ QFET® TinyBoost™ $\mathsf{FAST}^{\mathbb{R}}$ QSTM TinyBuck™ MicroFET™ FASTr™ MicroPak™ QT Optoelectronics™ TinyPWM™ Quiet Series™ FPS™ MICROWIRE™ TinyPower™ RapidConfigure™ FRFET™ TinyLogic[®] MSX™ MSXPro™ RapidConnect™ TINYOPTO™ μSerDes™ Across the board. Around the world.™ TruTranslation™ ScalarPump™ UHC™ The Power Franchise®

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

Programmable Active Droop™

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.

2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

Rev. I20